



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Shunpei Yamazaki, et al. Art Unit : 2823
Serial No.: 08/994,038 Examiner : W. David Coleman
Filed : December 18, 1997
Title : CHARGE TRANSFER SEMICONDUCTOR DEVICE AND MANUFACTURING
METHOD THEREOF

Box AF
Commissioner for Patents
Washington, D.C. 20231

AMENDMENT

In response to the Official Action dated July 3, 2001,
Paper No. 22, in the above-referenced application, please amend
the above-identified application as follows.

In the Claims:

Please amend the claims as follows:

1. (Amended) A charge transfer semiconductor device
comprising:
a crystalline semiconductor film having a plurality of
crystals extending in a crystal growth direction;

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being
deposited with the United States Postal Service as first class mail with
sufficient postage on the date indicated below and is addressed to the
Commissioner for Patents, Washington, D.C. 20231.

Date of Deposit

10-1-01

Signature

Susan M. Regan

Susan Regan

Typed or Printed Name of Person Signing Certificate

23/15 Amell
10/21/01
A. Well

RECEIVED
OCT 18 2001
TC 2800 MAIL ROOM